

2SK3065-VB Datasheet

N-Channel 60-V (D-S) MOSFET

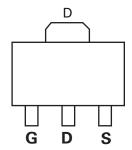
PRODUCT SUMMARY							
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)					
60	0.030 at V _{GS} = 10 V	8.0					
	0.034 at V _{GS} = 4.5 V	6.5					

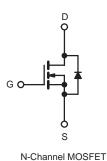
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETs
- 175 °C Maximum Junction Temperature
- Compliant to RoHS Directive 2002/95/EC



RoHS COMPLIANT





Parameter	Symbol	10 s	Steady State	Unit		
Drain-Source Voltage	V_{DS}		V			
Gate-Source Voltage	V_{GS}	±				
Continuous Drain Current (T _J = 175 °C) ^a	T _A = 25 °C	ls.	8.0	7.0		
Continuous Diairi Current (1 j = 175 °C)	T _A = 70 °C	I _D	6.4	5.6	Α	
Pulsed Drain Current	I _{DM}		A			
Avalanche Current	I _{AS}					
Single Pulse Avalanche Energy	E _{AS}		mJ			
Maniana Danian Disabation A	T _A = 25 °C	Pn	3.3	1.7	W	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	2.3	1.2	VV	
Operating Junction and Storage Temperature Rai	T _J , T _{stg}	- 55	°C			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	36	45			
Maximum Junction-to-Ambient	Steady State	\thJA	75	90	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	17	20			

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



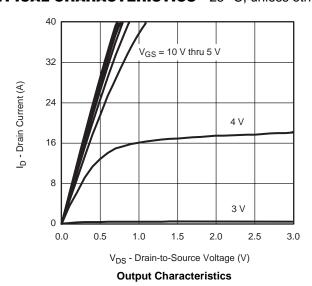
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		3	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	l	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
Zero Gate voltage Drain Current	IDSS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			20	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α
		V _{GS} = 10 V, I _D = 6.0 A		0.030		
Davis Course On Otata Basistana 3	D	$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}, T_J = 125 \text{ °C}$		0.035		Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}, T_J = 175 ^{\circ}\text{C}$		0.040		
	•	$V_{GS} = 4.5 \text{ V}, I_D = 5.1 \text{ A}$		0.034		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 6.0 \text{ A}$		25		S
Diode Forward Voltage ^a	V_{SD}	I _S = 1.7 A, V _{GS} = 0 V		0.8	1.2	V
Dynamic ^b			•			
Total Gate Charge	Q_g			18	27	
Gate-Source Charge	Q_{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 6.0 \text{ A}$		3.4		nC
Gate-Drain Charge	Q_{gd}			5.3		
Gate Resistance	R_g	$V_{GS} = 0.1 \text{ V, } f = 5 \text{ MHz}$	0.5	1.4	2.4	Ω
Turn-On Delay Time	t _{d(on)}			10	20	
Rise Time	t _r	V_{DD} = 30 V, R_L = 30 Ω		10	20	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		25	50	ns
Fall Time	t _f			12	24	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dI/dt = 100 A/μs		50	80	

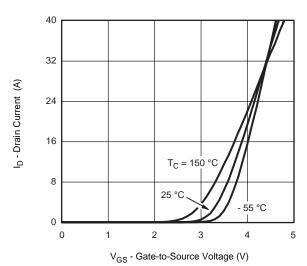
Notes:

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



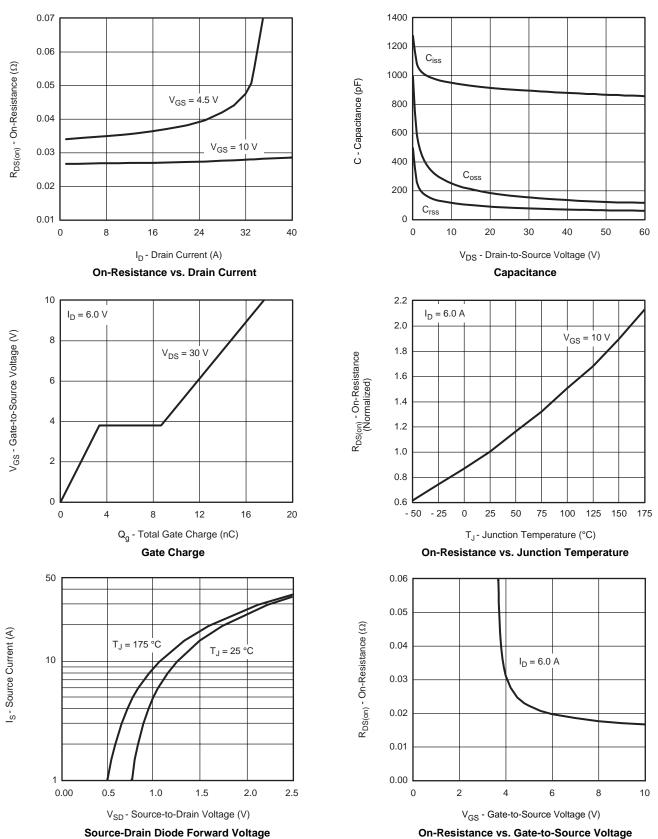


Transfer Characteristics

服务热线:400-655-8788



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





100

1000

10

3. T_{JM} - $T_A = P_{DM}Z_{thJA}^{(t)}$

100

600

4. Surface Mounted

10

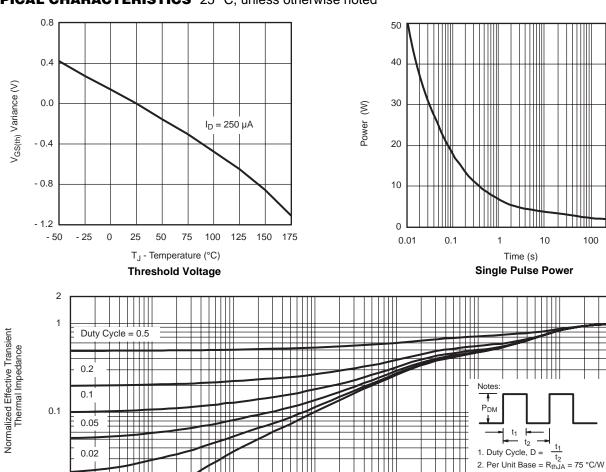
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Single Pulse

10-3

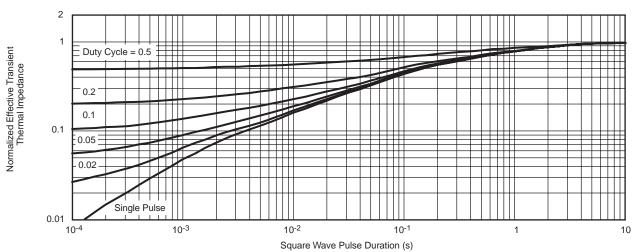
0.01

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10-2

Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Ambient

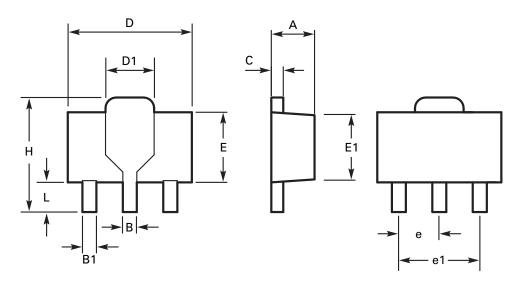


10-1

Normalized Thermal Transient Impedance, Junction-to-Foot



Package outline - SOT89



DIM	Millimeters		Inches		DIM	Millimeters		Inches			
	Min	Max	Min	Max		Min	Max	Min	Max		
Α	1.40	1.60	0.550	0.630	Е	2.29	2.60	0.090	0.102		
В	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090		
B1	0.36	0.48	0.014	0.019	е	1.50 BSC		0.059 BSC			
С	0.35	0.44	0.014	0.017	e1	3.00 BSC		1 3.00 BSC 0.1		0.118	BSC
D	4.40	4.60	0.173	0.181	Н	3.94	4.25	0.155	0.167		
D1	1.62	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047		

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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